

Current

#### 600V N-Channel MOSFET

600 V

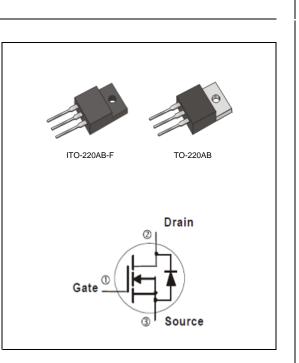
Voltage

#### Features

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V,I<sub>D</sub>@6A<0.7Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case : TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams



#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

12 A

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	UNITS
Drain-Source Voltage		V <sub>DS</sub>	600	V	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 30		V
Continuous Drain Current		I <sub>D</sub>	12		А
Pulsed Drain Current		I <sub>DM</sub>	48	А	
Single Pulse Avalanche Energy (Note 1)		E <sub>AS</sub>	795	mJ	
Power Dissipation	T <sub>c</sub> =25°C		225	51	W
	Derate above 25°C	PD	1.8	0.41	W/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150		°C
Typical Thermal resistance					
- Junction to Case		$R_{ extsf{ heta}JC}$	0.56	2.45	°C/W
- Junction to Ambient		$R_{ extsf{ heta}JA}$	62.5	120	



### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

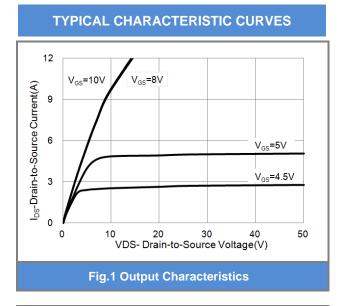
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	600	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	2	2.96	4	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =6A	-	0.59	0.7	Ω
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =600V,V <sub>GS</sub> =0V	-	0.02	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 30V,V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =12A,V <sub>GS</sub> =0V	-	0.85	1.4	V
Dynamic (Note 4)						
Total Gate Charge	Qg	1/ 4001/ 1 404	-	24	-	nC
Gate-Source Charge	$Q_gs$	V <sub>DS</sub> =480V, I <sub>D</sub> =12A, V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	7.8	-	
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =10V	-	7.4	-	
Input Capacitance	Ciss		-	1492	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	167	-	
Reverse Transfer Capacitance	Crss		-	4.5	-	
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DD</sub> =300V, I <sub>D</sub> =12A,	-	37	-	
Turn-On Rise Time	t <sub>r</sub>	R <sub>G</sub> =25Ω	-	72	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>	(Note 2,3)	-	81	-	
Turn-Off Fall Time	t <sub>f</sub>		-	44	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	1		-	-	12	A
Diode Forward Current	I <sub>S</sub>					
Maximum Pulsed Drain-Source			-	-	48	A
Diode Forward Current	I <sub>SM</sub>					
Reverse Recovery Time	trr	V <sub>GS</sub> =0V, I <sub>S</sub> =12A	-	574	-	ns
Reverse Recovery Charge	Qrr	dI <sub>F</sub> / dt=100A/us <sup>(Note 2)</sup>	-	5.4	-	uC

NOTES :

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- 1. L=30mH,  $I_{AS}$ =7.1A,  $V_{DD}$ =50V,  $R_{G}$ =250hm, Starting  $T_{J}$ =25°C
- 2. Pulse width</br>
- 3. Essentially independent of operating temperature typical characteristics.
- 4. Guaranteed by design, not subject to production testing





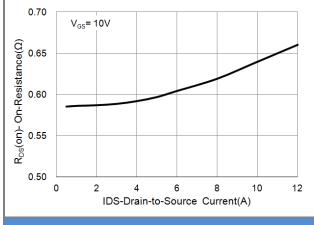
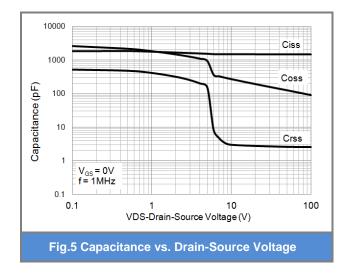
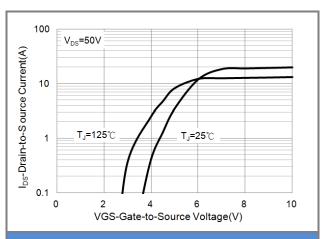


Fig.3 On-Resistance vs. Drain Current





**Fig.2 Transfer Characteristics** 

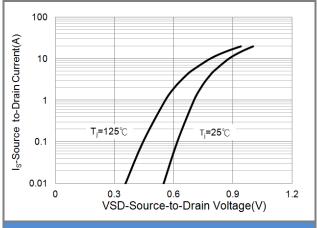
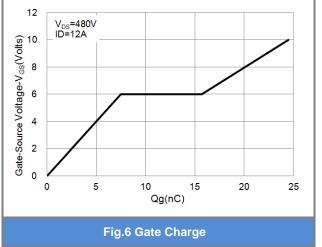


Fig.4 Source-Drain Diode Forward Voltage

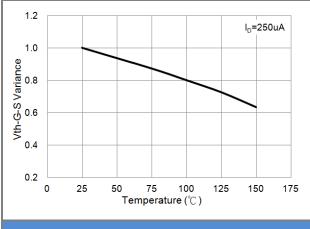


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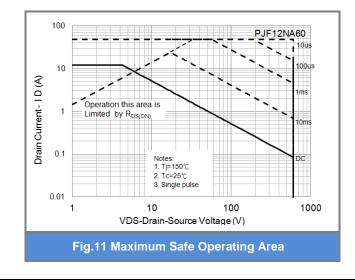


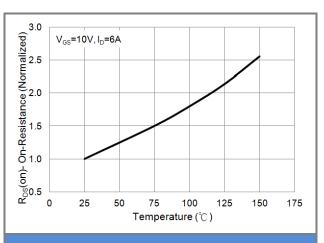
TYPICAL CHARACTERISTIC CURVES

Fig.7 BV<sub>DSS</sub> vs. Junction Temperature











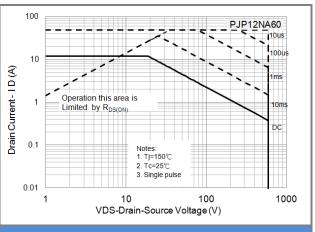


Fig.10 Maximum Safe Operating Area

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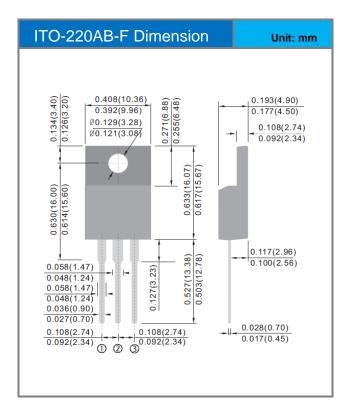


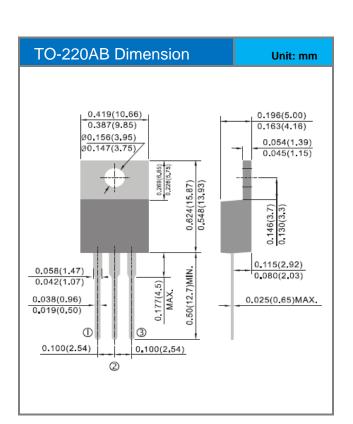
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#### **PJP12NA60 / PJF12NA60 TYPICAL CHARACTERISTIC CURVES** 10 ZTH.JC Normalized Transient Thermal Impedance 1 D=0.5 0.2 0.1 0.1 0.05 T<sub>J,PK</sub>=TC+P<sub>DM</sub>\*Z<sub>TH-JC</sub>\*R<sub>TH-JC</sub> R<sub>TH-JC</sub> = 0.56°C/W 0.02 0.01 0.01 TC = 25℃ Single Pulse $D = \frac{PW}{T}$ >w 0.001 0.00001 0.001 0.0001 0.01 0.1 1 10 t, Pulse Width (Sec) Fig.13 PJP12NA60 Normalized Transient Thermal Impedance vs. Pulse Width 10 ZTH-JC Normalized Transient Thermal Impedance 1 D=0.5 0.2 0.1 0.1 0.05 T<sub>J,PK</sub>=Tc+P<sub>DM</sub>\*Z<sub>TH-JC</sub>\*R<sub>TH-JC</sub> R<sub>TH-JC</sub> = 2.45°С/W 0.02 0.01 TC = 25℃ 0.01 $D = \frac{PW}{T}$ ingle P PW 0.001 0.00001 0.0001 0.001 0.01 0.1 1 10 t, Pulse Width (Sec) Fig.14 PJF12NA60 Normalized Transient Thermal Impedance vs. Pulse Width



#### Packaging Information





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#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJP12NA60_T0_00001	TO-220AB	50pcs / Tube	P12NA60	Halogen free
PJF12NA60_T0_00001	ITO-220AB-F	50pcs / Tube	F12NA60	Halogen free



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